

## CKC21C823FCGACTU

Aliases (CKC21C823FCGAC7800) KC-LINK Comm COG, Ceramic, 0.082 uF, 1%, 500 VDC, COG, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 2220, 3.5 mm



Click here for the 3D model.

General Information		
Series	KC-LINK Comm COG	
Style	SMD Chip	
Description	SMD, MLCC, Ultra-Stable, Low Loss, Class I	
Features	Ultra-Stable, Low Loss, Class I	
RoHS	Yes	
Termination	Tin	
Marking	No	
AEC-Q200	No	
Typical Component Weight	260 mg	
Shelf Life	78 Weeks	
MSL	1	

0% Loss/Decade Hour

12.1951 GOhms

	Specifications	
2220	Capacitance	0.082 uF
5.7mm +/-0.4mm	Measurement Condition	1 kHz 1.0Vrms
5mm +/-0.4mm	Tolerance	1%
2mm +/-0.20mm	Voltage DC	500 VDC
3.5mm MIN	Dielectric Withstanding Voltage	750 VDC
0.6mm +/-0.35mm	Temperature Range	-55/+150°C
	Temp. Coefficient	COG
	Capacitance Change with	30 ppm/C, 1kHz 1.0Vrms
T&R, 180mm, Plastic Tape	Reference to +25°C and 0 VDC Applied (TCC)	
500	Dissipation Factor	0.1% 1 kHz 1.0Vrms

Aging Rate

Insulation Resistance

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

Dimensions Chip Size

**Packaging Specifications** 

Packaging Quantity

L W

Т

s

В

Packaging



CKC21C823FCGACTU Aliases (CKC21C823FCGAC7800) KC-LINK Comm COG, Ceramic, 0.082 uF, 1%, 500 VDC, COG, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 2220, 3.5 mm

Capacitance and Inductance

1.0 n 0.6 n

0.4 n

0.3 n

100.0 p 63.1 p 🗄

0.2 n a

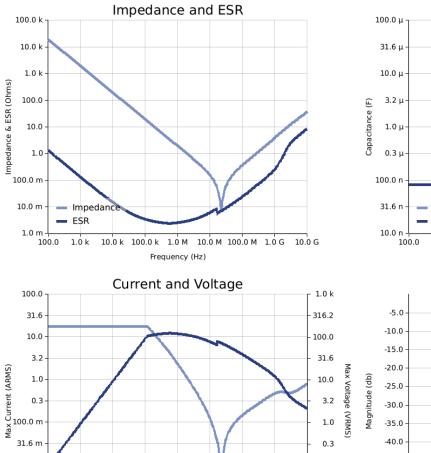
Phase

°

0.0

## Simulations

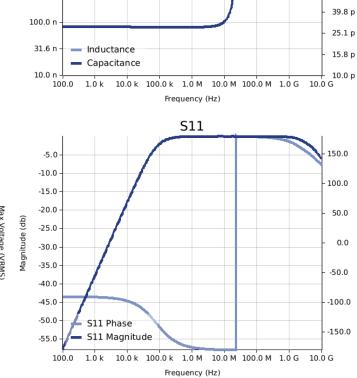
For the complete simulation environment please visit K-SIM.



100.0 m

31.6 m

10.0 m



S21 80.0 -10.0 60.0 40.0 -20.0 20.0 Magnitude (db) -30.0 Phase 0.0 -40.0 ° -20.0 -50.0 -40.0 -60.0 -60.0 S21 Phase S21 Magnitude -80.0 -70.0 1.0 k 10.0 k 100.0 k 1.0 M 10.0 M 100.0 M 1.0 G 10.0 G 100.0 Frequency (Hz)

Frequency (Hz)

10.0 k 100.0 k 1.0 M 10.0 M 100.0 M 1.0 G 10.0 G

10.0 m

3.2 m

1.0 m

100.0

Voltage

Current

1.0 k



## CKC21C823FCGACTU

Aliases (CKC21C823FCGAC7800) KC-LINK Comm COG, Ceramic, 0.082 uF, 1%, 500 VDC, COG, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 2220, 3.5 mm

## These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR used for hipple klipple current younge vs. requericy plots is the ESR at an bient temperature.
  The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
  The effects shown herein are based on measured data from a multiple part sample of the parts in question.
  Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
  The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages are not combined with voltages.
- generated at any other harmonics.
  Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.